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FDC8878

April 2015

N-Channel PowerTrench® MOSFET **30 V, 8.0 A, 16 m**Ω

Features

- Max $r_{DS(on)}$ = 16 m Ω at V_{GS} = 10 V, I_D = 8.0 A
- Max $r_{DS(on)}$ = 18 m Ω at V_{GS} = 4.5 V, I_D = 7.5 A
- High performance trench technology for extremely low r_{DS(on)}
- Fast switching speed
- RoHS Compliant

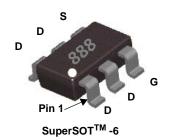
General Description

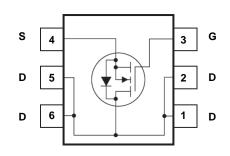
This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench® process that has been optimized for $r_{DS(on)}$, switching performance.

Applications

■ Primary Switch







MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DS}	Drain to Source Voltage		30	V
V _{GS}	Gate to Source Voltage	(Note 3)	±20	V
I _D	Drain Current -Continuous (Package limited) T _C = 25 °C		8.0	
	-Continuous T _A = 25 °C	(Note 1a)	8.0	Α
	-Pulsed		32	
D	Power Dissipation	(Note 1a)	1.6	10/
P_{D}	Power Dissipation	(Note 1b)	0.8	W
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	30	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	78	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
.888	FDC8878	SSOT-6	7 "	8 mm	3000 units

Electrical Characteristics $T_J = 25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	I _D = 250 μA, referenced to 25 °C		13		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 24 V, V _{GS} = 0 V			1	μΑ
I _{GSS}	Gate to Source Leakage Current, Forward	V _{GS} = 20 V, V _{DS} = 0 V			100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	1.2	1.6	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = 250 μ A, referenced to 25 °C		-5		mV/°C
r _{DS(on)}		$V_{GS} = 10 \text{ V}, I_D = 8.0 \text{ A}$		12	16	
	Static Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, I_D = 7.5 \text{ A}$		14	18	mΩ
		$V_{GS} = 10 \text{ V}, I_D = 8.0 \text{ A}, T_J = 125 °C$		16	21	
9 _{FS}	Forward Transconductance	$V_{DD} = 5 \text{ V}, I_{D} = 8.0 \text{ A}$		43		S

Dynamic Characteristics

C _{iss}	Input Capacitance	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz	782	1040	pF
C _{oss}	Output Capacitance		318	425	pF
C _{rss}	Reverse Transfer Capacitance		40	60	pF
R_g	Gate Resistance		1.2		Ω

Switching Characteristics

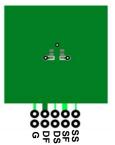
t _{d(on)}	Turn-On Delay Time		6	12	ns
t _r	Rise Time	V _{DD} = 15 V, I _D = 8 A,	2	10	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, R_{GEN} = 6 \Omega$	17	30	ns
t _f	Fall Time		2	10	ns
0	Total Gate Charge	V _{GS} = 0 V to 10 V	13	18	nC
$Q_{g(TOT)}$	Total Gate Charge	$V_{GS} = 0 \text{ V to } 4.5 \text{ V}$ $V_{DD} = 15 \text{ V}$	6	9	nC
Q_{gs}	Total Gate Charge	I _D = 8 A	1.7		nC
Q_{gd}	Gate to Drain "Miller" Charge		2.0		nC

Drain-Source Diode Characteristics

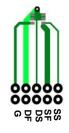
V_{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{S} = 8.0 \text{ A}$	(Note 2)	0.8	1.2	V
t _{rr}	Reverse Recovery Time	- I _F = 8.0 A, di/dt = 100 A/μs		22	35	ns
Q_{rr}	Reverse Recovery Charge			7	14	nC

NOTES

 $R_{0.0}$ is guaranteed by design while $R_{0.0}$ is determined by the user's board design.



a. 78 °C/W when mounted on a 1 in² pad of 2 oz copper



b.175 °C/W when mounted on a minimum pad of 2 oz copper

- 2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0 %.
- 3. As an N-ch device, the negative Vgs rating is for low duty cycle pulse occurrence only. No continuous rating is implied.

Typical Characteristics T_J = 25°C unless otherwise noted

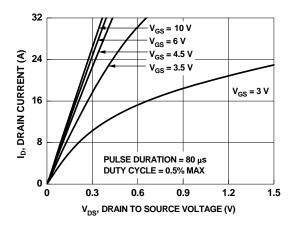


Figure 1. On Region Characteristics

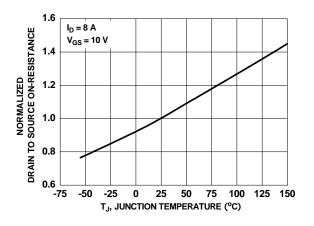


Figure 3. Normalized On Resistance vs Junction Temperature

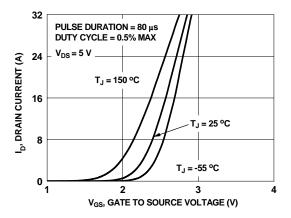


Figure 5. Transfer Characteristics

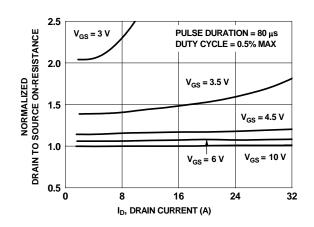


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

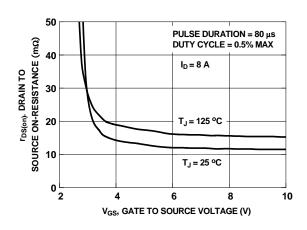


Figure 4. On-Resistance vs Gate to Source Voltage

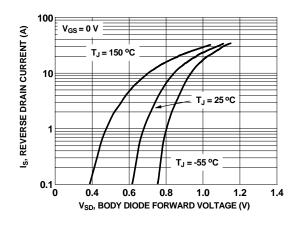


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics T_J = 25°C unless otherwise noted

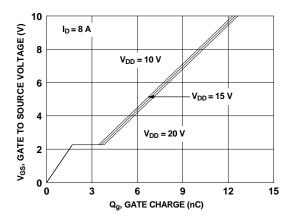


Figure 7. Gate Charge Characteristics

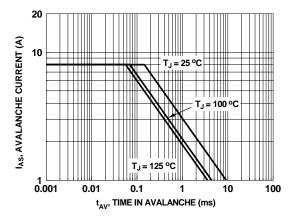


Figure 9. Unclamped Inductive Switching Capability

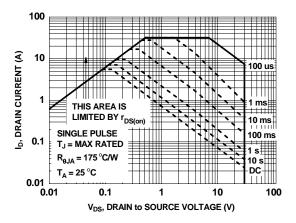


Figure 11. Forward Bias Safe Operating Area

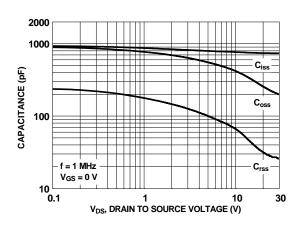


Figure 8. Capacitance vs Drain to Source Voltage

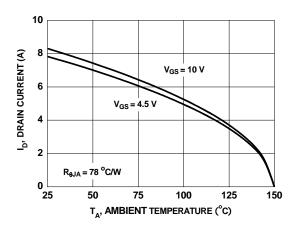


Figure 10. Maximum Continous Drain Current vs. Ambient Temperature

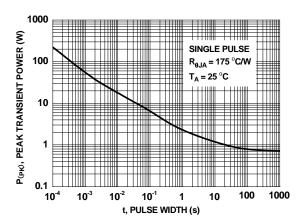


Figure 12. Single Pulse Maximum Power Dissipation

Typical Characteristics T_J = 25°C unless otherwise noted

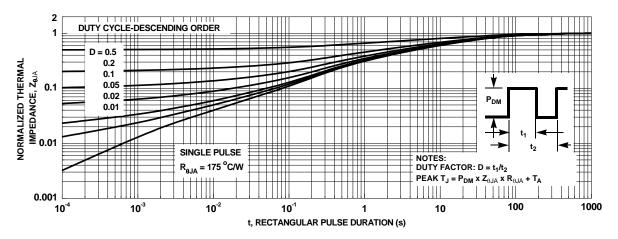
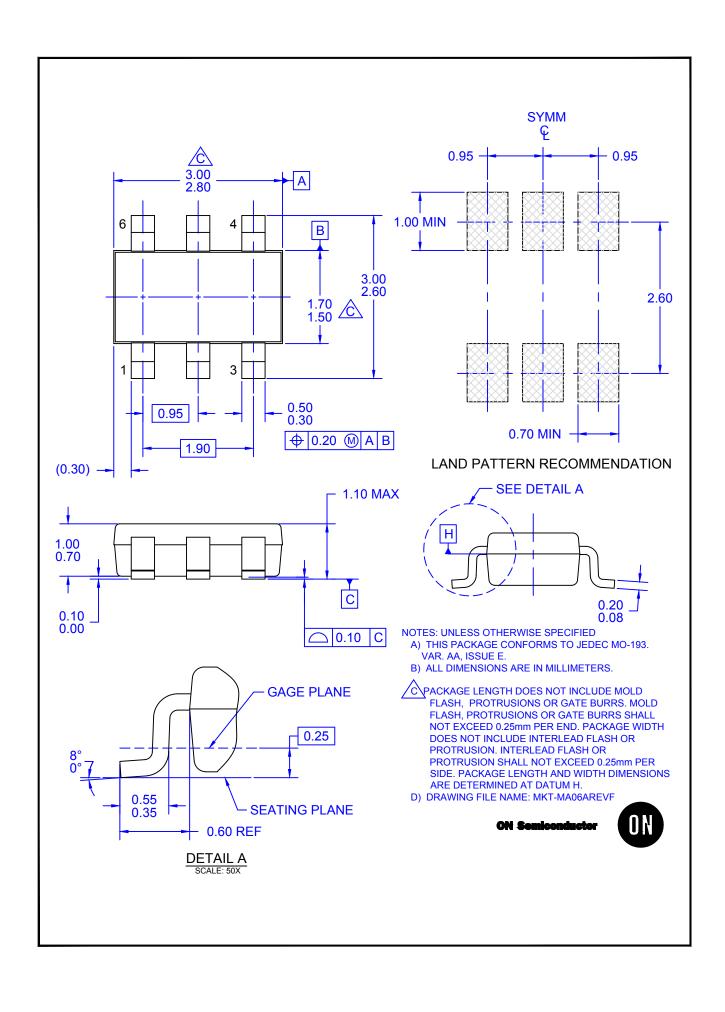


Figure 13. Junction-to-Ambient Transient Thermal Response Curve



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